

Forward Looking Statements



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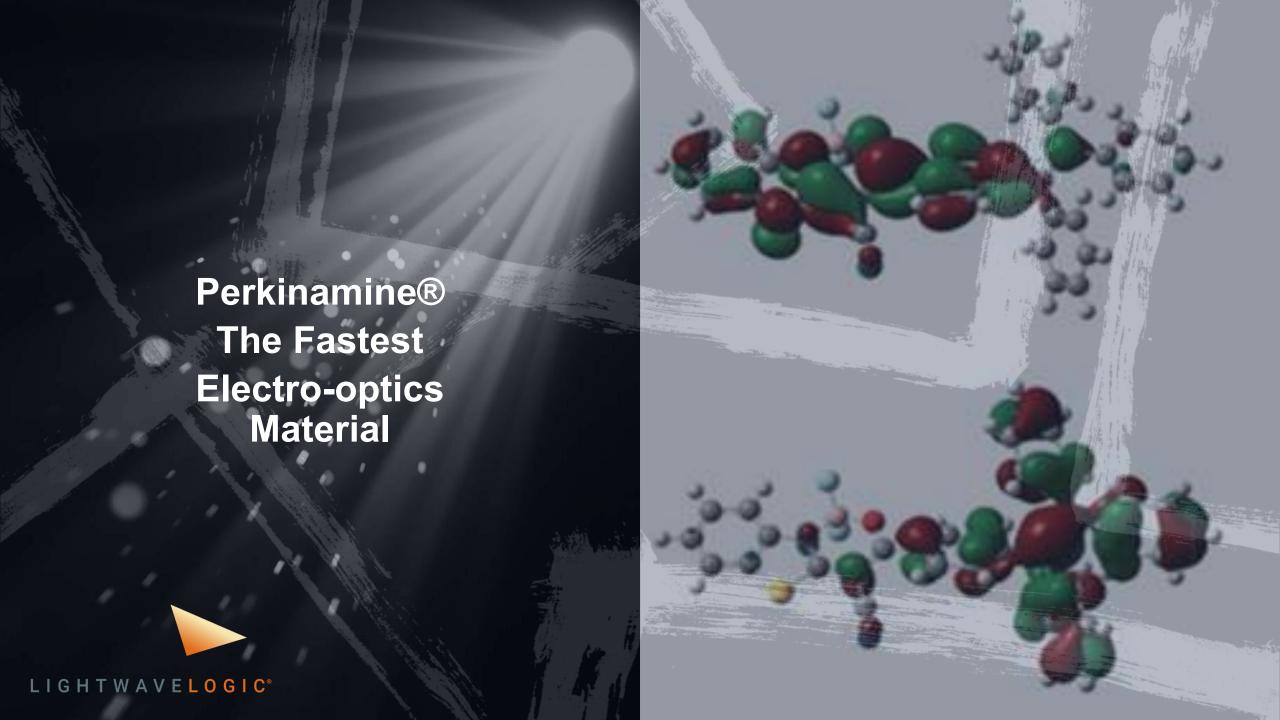
All forward-looking statements are based on current beliefs as well as various assumptions made by, and information currently available to the company's management team. A more detailed description of the risks presented by those assumptions and other risks are more fully described by the company under the caption "Risk Factors" included in our SEC filings and other risks to which our company is subject, and various other factors beyond the company's control.

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Imagine a flashlight turning on and off 100 billion times per second





Al Infrastructure Facing New Challenges



BANDWIDTH

CONNECTIVITY

POWER

INTEGRATION

Al Cluster Opportunity



Scale Out – Switch Rack to Switch Rack interconnect using optics (transceiver based)







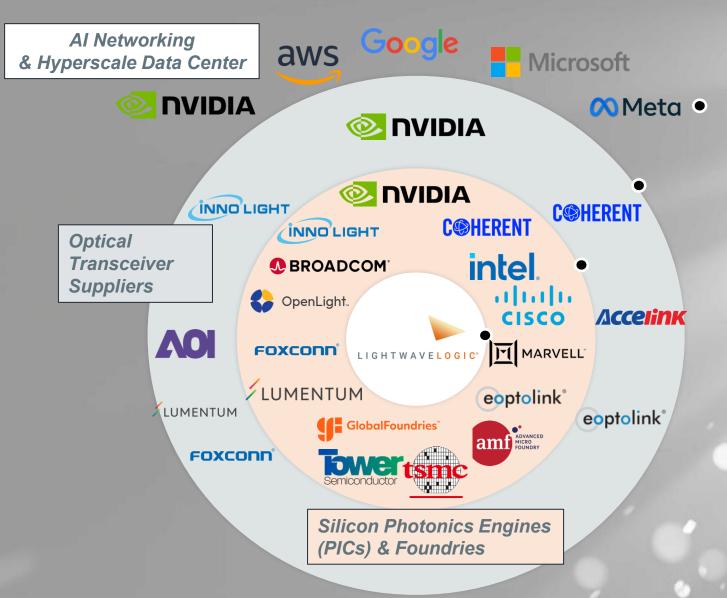


Scale Out – GPU rack to Switch rack connectivity – migrating to optical cables/CPO

Scale Up – GPU to GPU connectivity – PCB traces migrating to CPO/optical chiplets

Source: Nvidia

Enabling AI Connectivity Ecosystem

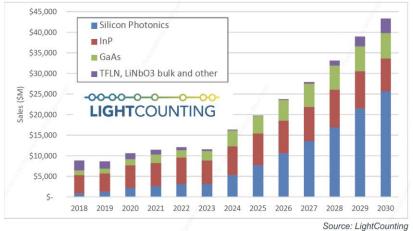




Silicon Photonics for Al Scale Up and Scale Out 200G and 400G speeds needed for \$15B Opportunity in 2030

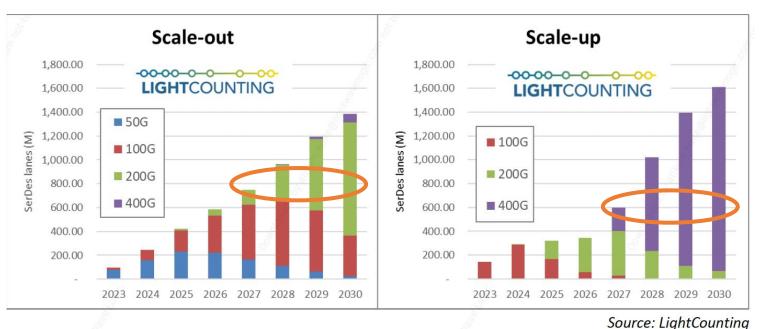


Sales of optical transceivers by technology





SERDES Speeds Transition



- 200G Scale out and 400G Scale up Photonics needed in 2027 timeframe
- Traditional SiPh needs to be augmented to reach 400G and improve
 200G performance
- EO Polymers offer viable path compatible with standard CMOS processing and assembly

2028 Estimated Total Addressable Market (TAM) & Serviceable Addressable Market (SAM)*

\$10 billion TAM ΑI 20M units of 1.6Tb/s and 3.2Tb/s transceivers/CPO (200Gb/s+ lane) = 160M modulators \$1.0 - 2.5 billion SAM \$7 billion TAM Datacenter Serviceable market for EOP 18M units of high-speed modulators depending on transceivers (100Gb/s+ per lane) integration level = 70*M* modulators Potential additional markets \$7 billion TAM (not included): **Quantum Computing** Telecom 2M units of coherent DWDM Aerospace & Defense Consumer Electronics transceivers - 4M modulators



Our Business Model Material + IP/Royalty Licensing Company



Foundational E/O Polymer R&D...

...For Creating
Next-Gen Optical
Modulators

...And Generating High Margin Revenues



E/O Polymer Composition & IP

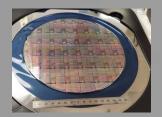


E/O Polymer Production



Material Sales

60%+



Reference Designs & Polymer "PDK" IP



IP & "PDK" Licensing & "Co-Design" Capability



Licensing &/or Royalty Fees

Gross Margin at Scale



Stage 1 Complete

Technology & Materials
Development

Patents/IP, Polymers, Factory and Process **Stage 2** 2025 + 2026

Customers & Products

Product Design-ins
Silicon Photonics
Foundries
Al Ecosystem

Integration

Stage 3
Starting 2026

Scale-up & Diversification

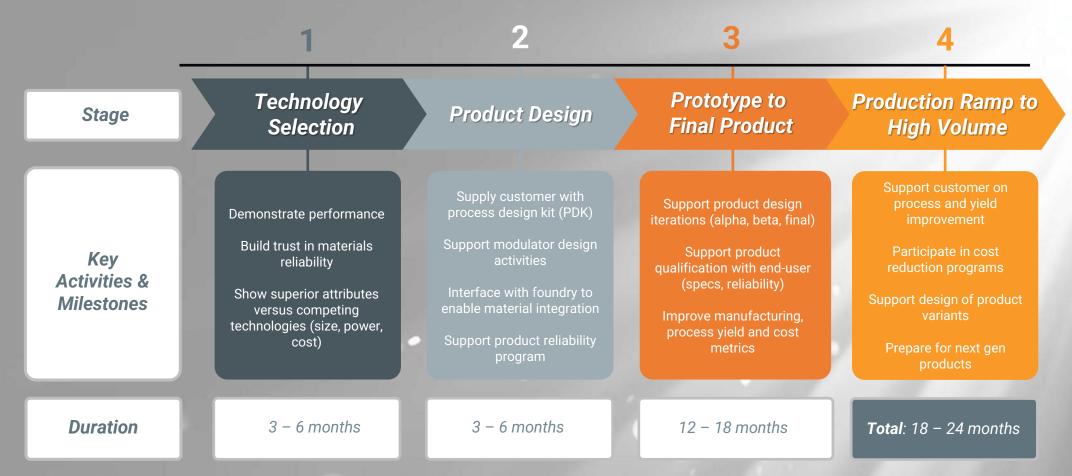
Production
infrastructure
+
New markets and

applications





Design Win Cycle

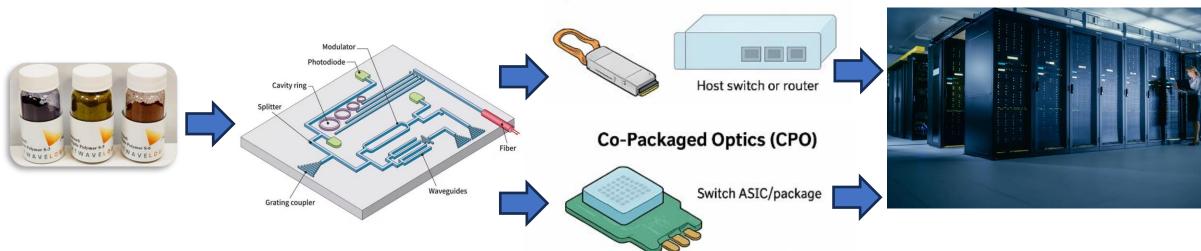


Reaffirming expectation to have 3-5 customers in Stage 3 by year-end 2025



LIGHTWAVELOGIC®

Optical Transceiver Modules



Perkinamine **EO** Polymer



Silicon Photonics PIC (Photonics **Integrated Circuit)**



Integrated Optical Module



Datacenter or Al Factory

















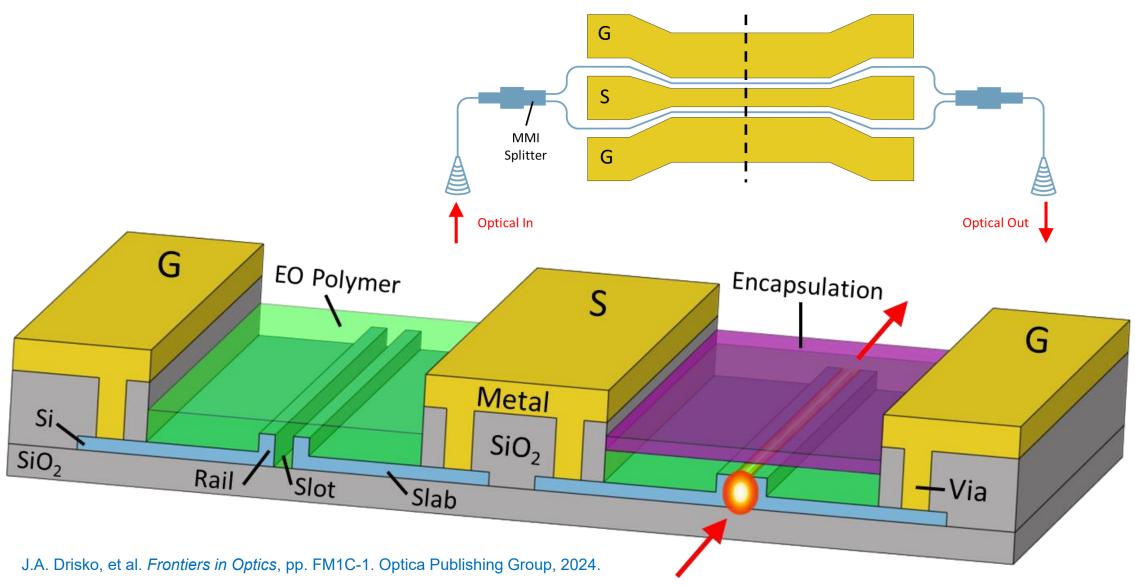






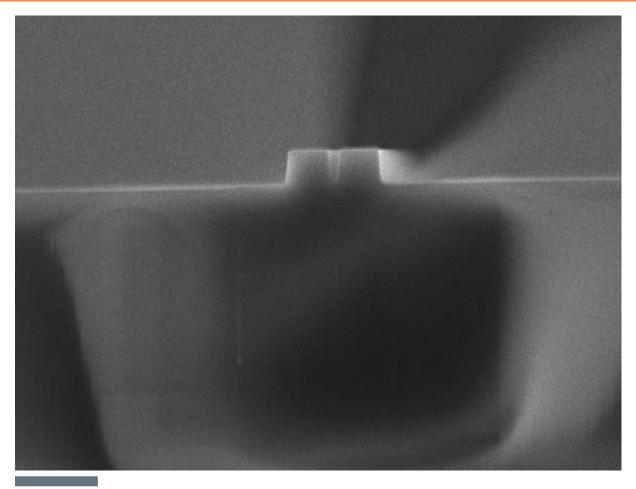
Polymer Slot Modulators

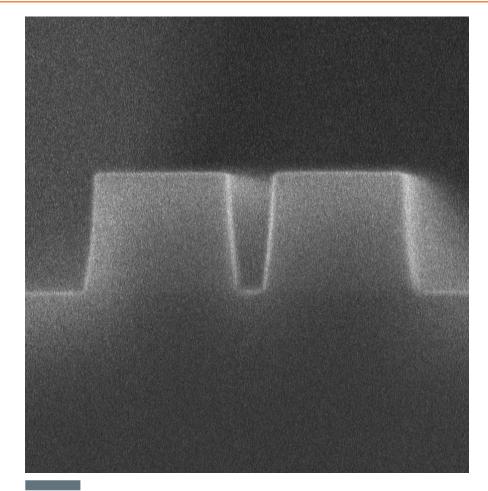




Si Slot Waveguide Cross Sections







500 nm

100 nm

Clean, sharp, and smooth Si slots

Electro-Optic Polymers (EOPs) - Perkinamine®



LIGHTWAVELOGIC°

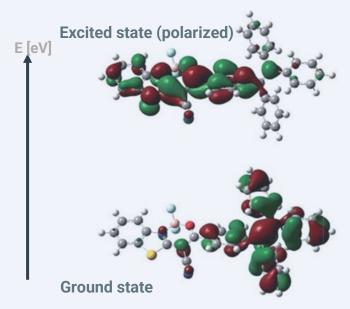
General chromophore structure Donor Bridge Acceptor CN CN CN CN

Chromophores are dipolar molecules



Pockels Effect:

- Linear electro-optic effect with the fastest response time
- Refractive index change directly proportional to applied electric field
- Occurs in non-centrosymmetric materials



The electric field shifts the electron cloud to the excited-state molecular orbitals.

This alters the refractive index of the electro-optic material, which in turn causes a phase change to any transiting optical signal

EOPs: Index change proportional to applied field with the fastest response time

Comparison of Key Modulator Technologies LIGHTWAY



LWLG EO polymers have inherently high performance and are fully Si-foundry compatible

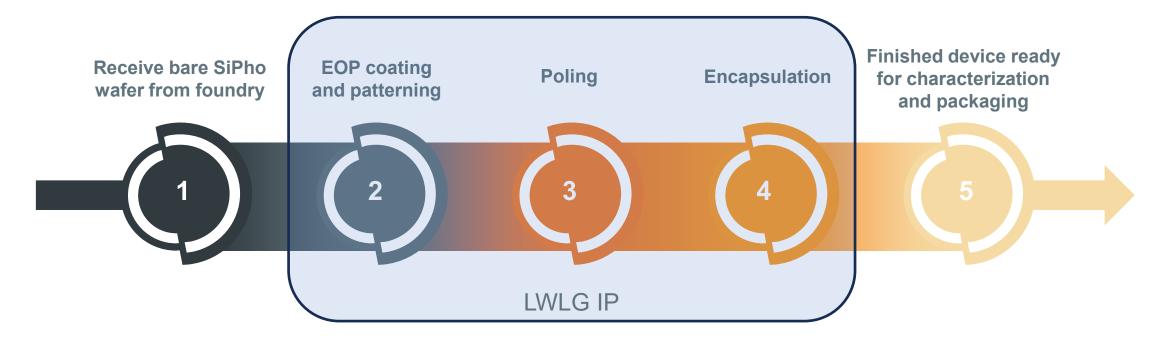
	Silicon Organic Hybrids (SiPh+EOP)	Thin Film Lithium Niobate (TFLN)	Silicon Photonics (SiPh)		Indium Phosphide (InP)	
Modulator Type	MZ or Ring	MZ	Ring	Mach-Zehnder (MZ)	DFB-MZ	Diff EML
Modulation Speed	•	•	•	•	•	•
Power Consumption	•	•	•	•	•	•
Drive Voltage (at 200G)	•	•	•	•	•	•
Size	•	•	•	•	•	•
Cost	•	•	•	•	•	•
Reliability	•	•		•	•	•
Bias Drift / Control complexity	•	•	•	•	•	•
Ease of Integration / Scalability / 300mm Compatible	•	•	•	•	•	•
		ı		Incumbent 7	Incumbent Technologies	

CMOS Compatible Process Flow

Fully compatible and integrable with SiPho foundry process

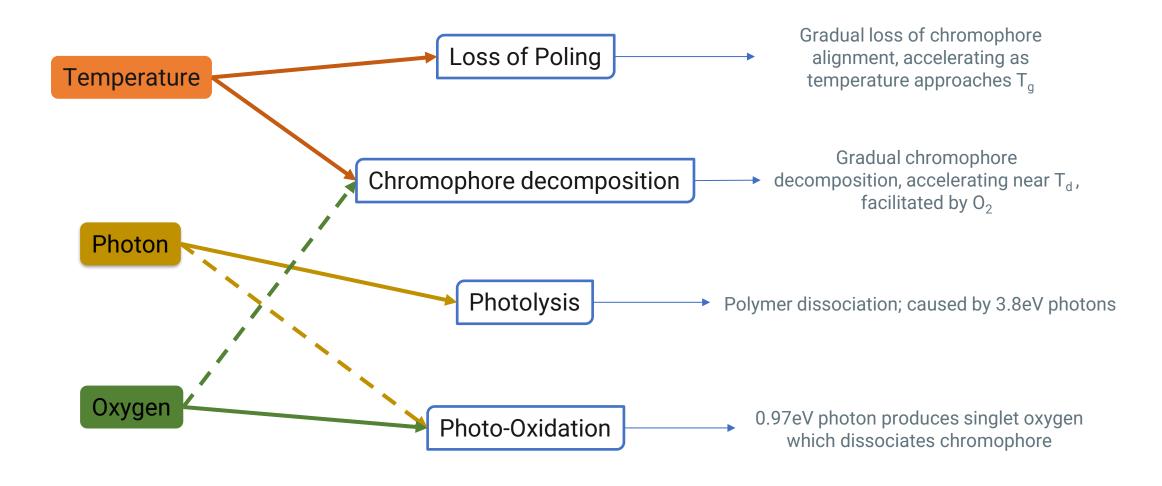
LWLG Backend/Encapsulation Process:

Currently performed in-house; fully documented and ready for transfer to the foundry



Understanding Reliability Challenges





Oxygen is the primary stressor

Perkinamine® Reliability Breakthrough



Successful passing of Telcordia GR-468 85/85 environmental stress test validates long-term reliability



Sample Selection

Thin-film devices with second-generation proprietary encapsulation barrier



Stress Conditions

- 85 °C and 85 % relative humidity for 1,000 hours
 - Industry standard rigorous conditions



Performance

 Change in absorbance measurements showed only 1.6% average loss after 1,000 hours



Pass Rate

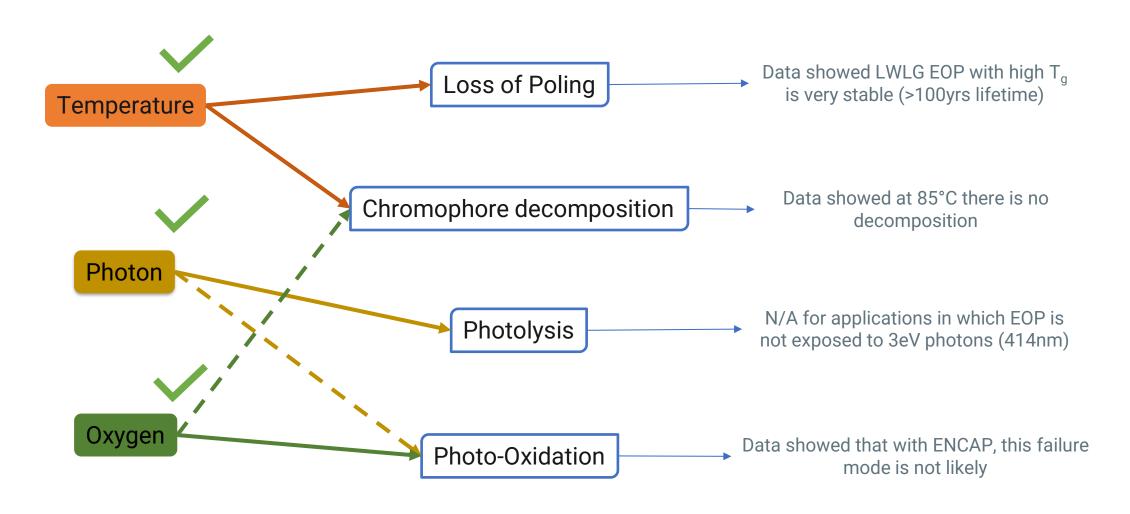
More than 11 samples exceeded Telcordia
 GR-468 requirements by a wide margin

- ✓ Confirmation that our EO polymer materials can **maintain performance** over time in harsh operating conditions
- ✓ Similarities with the **trajectory of Organic LEDs** before deployment in real-world applications
- ✓ Robust protection against moisture and oxygen
- ✓ Significant breakthrough with **fourthgeneration atomic layer deposition** (ALD) encapsulation material

Proof of reliability is critical to convince customers to proceed in design win cycle

Reliability Data Summary





All Key Reliability Challenges Addressed

Backend Process: Introduction

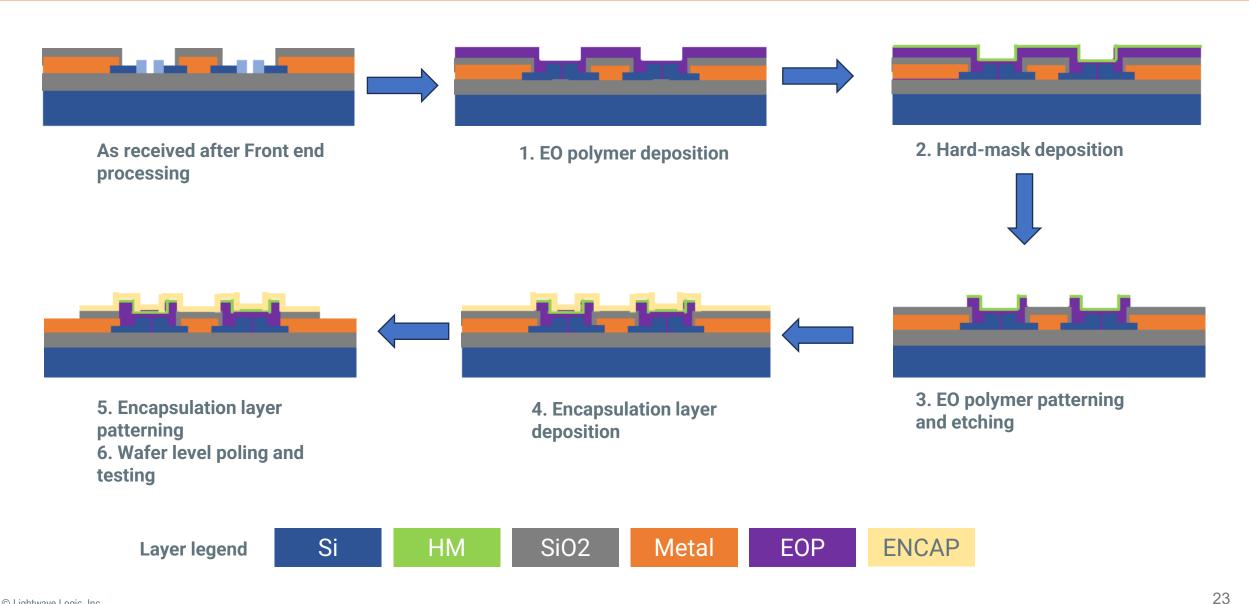


- The backend PDK is developed for applying EO polymers on the modulator device fabricated by a standard silicon photonics process (not foundry-specific)
- Key PDK steps
 - EO Polymer Deposition
 - EO Polymer Patterning and Etching
 - Encapsulation
 - Contact Pad Opening
- Wafer Level Poling and Test
- The manufacturing process is compatible with semiconductor fabrication lines using standard high-volume tools

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Simplified Backend Process Overview

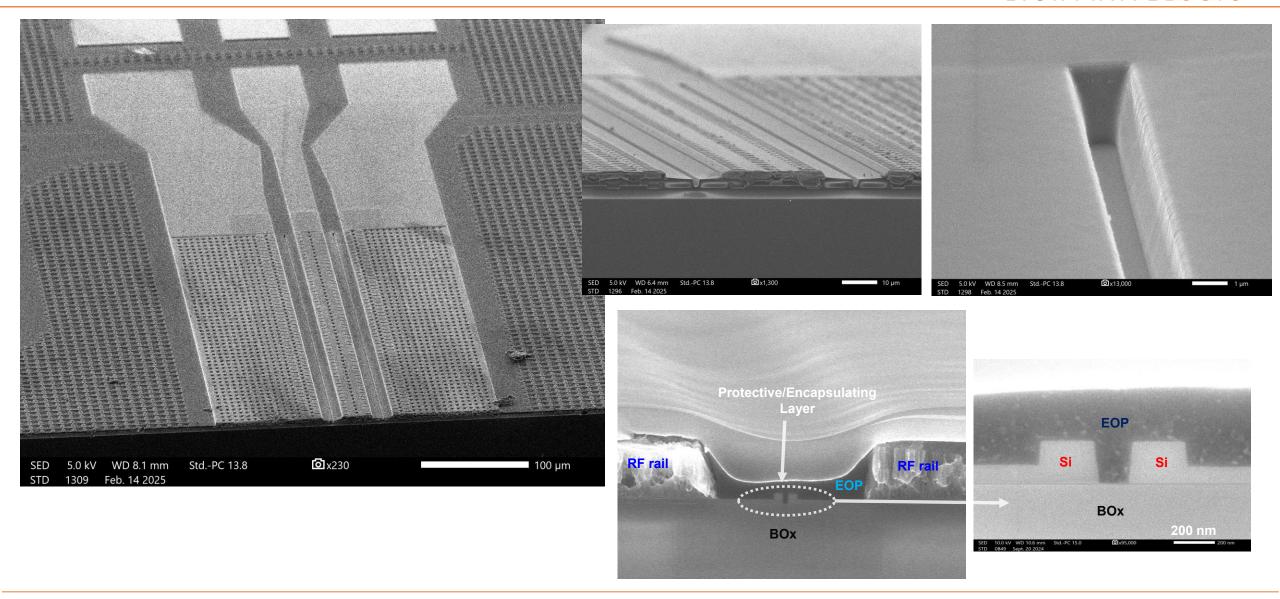




Example Device SEMs after EO Polymer Integration



LIGHTWAVELOGIC®



Key Takeaways





Unprecedented Accelerating Demand

- TAM of \$24B and SAM of \$1-2.5B by 2028 are growing quickly
- Driven by CapEx to address Al, quantum, datacomm & space comm requirements



Innovative EO Polymer Technology

- Disruptive technology enabler for future speed upgrades in data bandwidth
- Relieves key bottlenecks in Al infrastructure



Strong Patent Portfolio

- Protected by broad IP portfolio with over 70 patents
- · Numerous patents pending



Deeply Experienced Leadership

 Management, Board of Directors, Advisory Board have 200+ years conceiving and launching products



Robust Balance Sheet

- · Critical for execution
- \$35M cash position provides significant optionality and execution runway (as of 9/30/25)



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